MOTOROLA

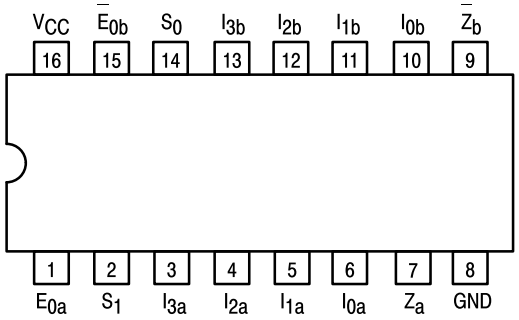
SN54/74LS353

DUAL 4-INPUT MULTIPLEXER WITH 3-STATE OUTPUTS

The LSTTL/MSI SN54/74LS353 is a Dual 4-Input Multiplexer with 3-state outputs. It can select two bits of data from four sources using common select inputs. The outputs may be individually switched to a high impedance state with a HIGH on the respective Output Enable (E_0) inputs, allowing the outputs to interface directly with bus oriented systems. It is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all TTL families.

- Inverted Version of the SN54/74LS253
- Schottky Process for High Speed
- Multifunction Capability
- Input Clamp Diodes Limit High Speed Termination Effects

CONNECTION DIAGRAM DIP (TOP VIEW)



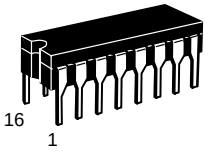
NOTE:
The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

PIN NAMES		LOADING (Note a) HIGH	LOW
S_0, S_1	Common Select Inputs	0.5 U.L.	0.25 U.L.
Multiplexer A			
E_{0a}	Output Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
$I_{0A}-I_{3a}$	Multiplexer Inputs	0.5 U.L.	0.25 U.L.
Z_a	Multiplexer Output (Note b)	65 (25) U.L.	15 (7.5) U.L.
Multiplexer B			
E_{0b}	Output Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
$I_{0b}-I_{3b}$	Multiplexer Inputs	0.5 U.L.	0.25 U.L.
Z_b	Multiplexer Output (Note b)	65 (25) U.L.	15 (7.5) U.L.

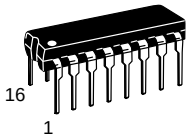
NOTES:
a) 1 TTL Unit Load (U.L.) = 40 μA HIGH/1.6 mA LOW.
b) The Output LOW drive factor is 7.5 U.L. for Military (54) and 15 U.L. for Commercial (74) Temperature Ranges. The Output HIGH drive factor is 25 U.L. for Military and 65 U.L. for Commercial Temperature Ranges.

DUAL 4-INPUT MULTIPLEXER WITH 3-STATE OUTPUTS

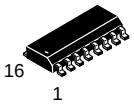
LOW POWER SCHOTTKY



J SUFFIX
CERAMIC
CASE 620-09



N SUFFIX
PLASTIC
CASE 648-08

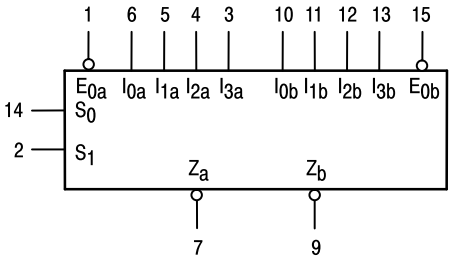


D SUFFIX
SOIC
CASE 751B-03

ORDERING INFORMATION

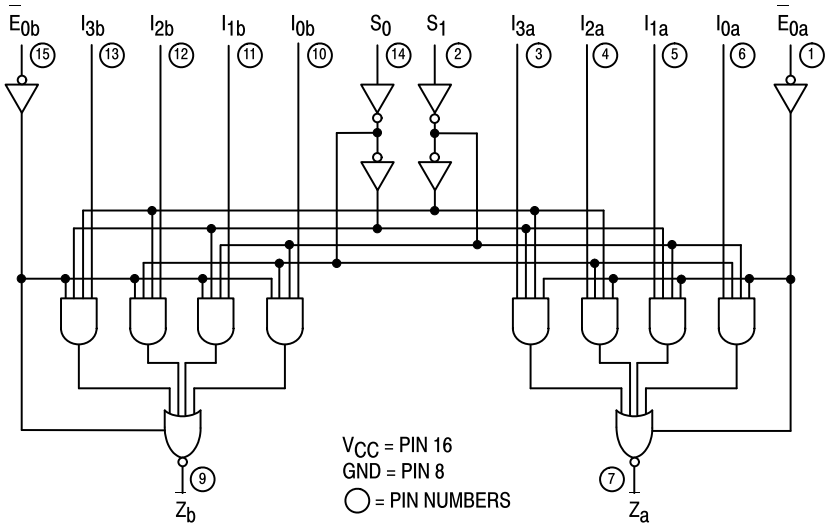
SN54LSXXXJ	Ceramic
SN74LSXXXN	Plastic
SN74LSXXXD	SOIC

LOGIC SYMBOL



V_{CC} = PIN 16
GND = PIN 8

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The SN54/74LS353 contains two identical 4-input Multiplexers with 3-state outputs. They select two bits from four sources selected by common select inputs (S_0, S_1). The 4-input multiplexers have individual Output Enable (E_{0a}, E_{0b}) inputs which when HIGH, forces the outputs to a high impedance (high Z) state.

The logic equations for the outputs are shown below:

$$\overline{Z}_a = \overline{\overline{E}_{0a} \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + I_{2a} \bullet S_1 \bullet \overline{S}_0 + I_{3a} \bullet S_1 \bullet S_0)}$$

$$\overline{Z}_b = \overline{\overline{E}_{0b} \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1b} \bullet \overline{S}_1 \bullet S_0 + I_{2b} \bullet S_1 \bullet \overline{S}_0 + I_{3b} \bullet S_1 \bullet S_0)}$$

If the outputs of 3-state devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-state devices whose outputs are tied together are designed so that there is no overlap.

TRUTH TABLE

SELECT INPUTS		DATA INPUTS				OUTPUT ENABLE	OUTPUT
S_0	S_1	I_0	I_1	I_2	I_3	$\overline{E}_0$	Z
X	X	X	X	X	X	H	(Z)
L	L	L	X	X	X	L	H
L	L	H	X	X	X	L	L
H	L	X	L	X	X	L	H
H	L	X	H	X	X	L	L
L	H	X	X	L	X	L	H
L	H	X	X	H	X	L	L
H	H	X	X	X	L	L	H
H	H	X	X	X	H	L	L

H = HIGH Level
L = LOW Level
X = Immaterial
(Z) = High Impedance (off)
Address inputs S_0 and S_1 are common to both sections.

GUARANTEED OPERATING RANGES

Symbol	Parameter		Min	Typ	Max	Unit
V_{CC}	Supply Voltage	54 74	4.5 4.75	5.0 5.0	5.5 5.25	V
T_A	Operating Ambient Temperature Range	54 74	–55 0	25 25	125 70	°C
I_{OH}	Output Current — High	54 74			–1.0 –2.6	mA
I_{OL}	Output Current — Low	54 74			12 24	mA

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter		Limits Min	Limits Typ	Limits Max	Unit	Test Conditions	
V_{IH}	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V_{IL}	Input LOW Voltage	54			0.7	V	Guaranteed Input LOW Voltage for All Inputs	
		74			0.8			
V_{IK}	Input Clamp Diode Voltage			–0.65	–1.5	V	V_{CC} = MIN, I_{IN} = –18 mA	
V_{OH}	Output HIGH Voltage	54	2.4	3.4		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
		74	2.4	3.1		V		
V_{OL}	Output LOW Voltage Q_A–Q_H	54, 74		0.25	0.4	V	I_{OL} = 12 mA	V_{CC} = V_{CC} MIN, V_{IN} = V_{IL} or V_{IH} per Truth Table
		74		0.35	0.5	V	I_{OL} = 24 mA	
I_{OZH}	Output Off Current HIGH				20	µA	V_{CC} = MAX, V_{OUT} = 2.7 V	
I_{OZL}	Output Off Current LOW				–20	µA	V_{CC} = MAX, V_{OUT} = 0.4 V	
I_{IH}	Input HIGH Current				20	µA	V_{CC} = MAX, V_{IN} = 2.7 V	
					0.1	mA	V_{CC} = MAX, V_{IN} = 7.0 V	
I_{IL}	Input LOW Current				–0.4	mA	V_{CC} = MAX, V_{IN} = 0.4 V	
I_{OS}	Short Circuit Current (Note 1)		–20		–130	mA	V_{CC} = MAX	
I_{CC}	Power Supply Current Total, Output 3-State				14	mA	V_{CC} = MAX	
	Total, Output LOW				12			

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

Symbol	Parameter	Limits Min	Limits Typ	Limits Max	Unit	Test Conditions	
t_{PLH} t_{PHL}	Propagation Delay, Data to Output		11 13	25 20	ns	Figure 1	C_L = 15 pF
t_{PLH} t_{PHL}	Propagation Delay, Select to Output		20 21	45 32	ns	Figure 1 or 2	
t_{PZH}	Output Enable Time to HIGH Level		11	23	ns	Figures 4, 5	
t_{PZL}	Output Enable Time to LOW Level		15	23	ns	Figures 3, 5	
t_{PLZ}	Output Disable Time to LOW Level		12	27	ns	Figures 3, 5	C_L = 5.0 pF
t_{PHZ}	Output Disable Time to HIGH Level		27	41	ns	Figures 4, 5	

3-STATE WAVEFORMS

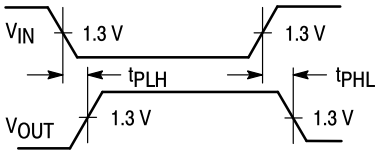


Figure 1

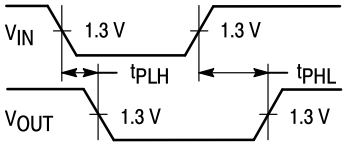


Figure 2

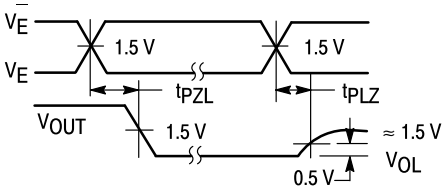


Figure 3

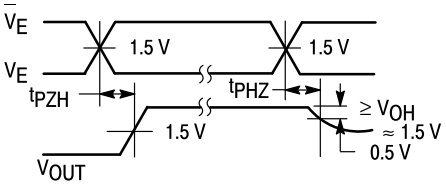
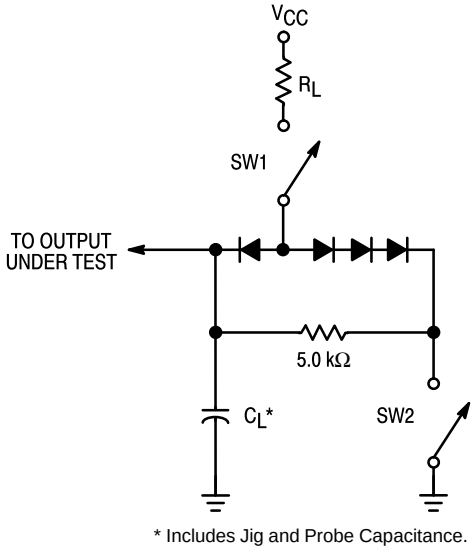


Figure 4

AC LOAD CIRCUIT



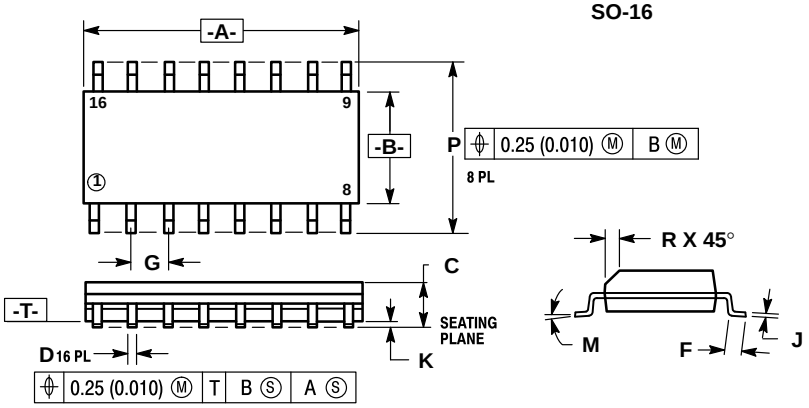
* Includes Jig and Probe Capacitance.

SWITCH POSITIONS

SYMBOL	SW1	SW2
t_{PZH}	Open	Closed
t_{PZL}	Closed	Open
t_{PLZ}	Closed	Closed
t_{PHZ}	Closed	Closed

Figure 5

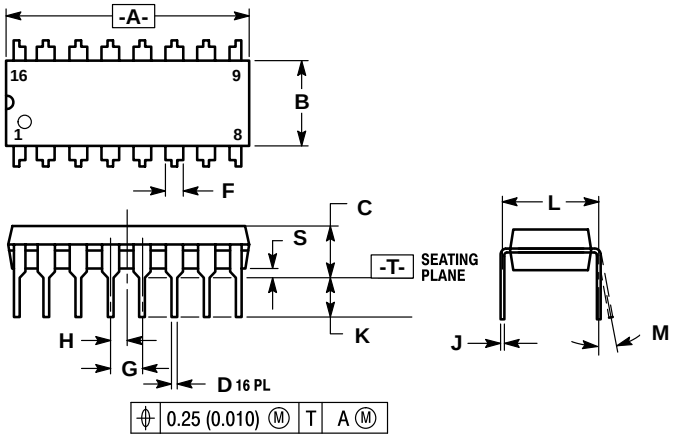
Case 751B-03 D Suffix
16-Pin Plastic
SO-16



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. 751B-01 IS OBSOLETE, NEW STANDARD 751B-03.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

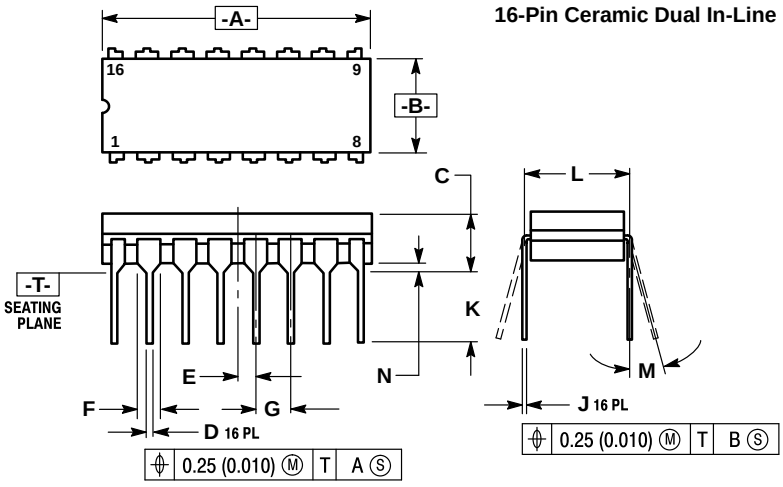
Case 648-08 N Suffix
16-Pin Plastic



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION "B" DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.
6. 648-01 THRU -07 OBSOLETE, NEW STANDARD 648-08.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	18.80	19.55	0.740	0.770
B	6.35	6.85	0.250	0.270
C	3.69	4.44	0.145	0.175
D	0.39	0.53	0.015	0.021
F	1.02	1.77	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	1.27 BSC		0.050 BSC	
J	0.21	0.38	0.008	0.015
K	2.80	3.30	0.110	0.130
L	7.50	7.74	0.295	0.305
M	0°	10°	0°	10°
S	0.51	1.01	0.020	0.040

Case 620-09 J Suffix
16-Pin Ceramic Dual In-Line



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIM F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.
5. 620-01 THRU -08 OBSOLETE, NEW STANDARD 620-09.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	19.05	19.55	0.750	0.770
B	6.10	7.36	0.240	0.290
C	—	4.19	—	0.165
D	0.39	0.53	0.015	0.021
E	1.27 BSC		0.050 BSC	
F	1.40	1.77	0.055	0.070
G	2.54 BSC		0.100 BSC	
J	0.23	0.27	0.009	0.011
K	—	5.08	—	0.200
L	7.62 BSC		0.300 BSC	
M	0°	15°	0°	15°
N	0.39	0.88	0.015	0.035

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